# NSN 5961-01-200-4076

Transistor - Page 1 of 2



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#### **Inclosure Material:**

Metal

### **Overall Length:**

Between 0.240 inches and 0.260 inches

#### **Terminal Length:**

Between 1.500 inches and 1.750 inches

#### **Overall Diameter:**

Between 0.335 inches and 0.370 inches

#### **Function For Which Designed:**

Amplifier

#### **Internal Configuration:**

Junction contact

#### **Electrode Internally-electrically Connected To Case:**

Collector

**Mounting Method:** 

Terminal

# **Terminal Circle Diameter:**

0.200 inches

#### **Semiconductor Material:**

Silicon

# Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

500.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

5.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

# **Special Features:**

Junction pattern arrangement: npn

# **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

3 uninsulated wire lead

# **Specification Data:**

81349-mil-s-19500/366 government specification

# Shelf Life:

N/a

# Unit Of Measure:

- **Demilitarization:**

# **NSN 5961-01-200-4076** Transistor - Page 2 of 2

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